



**UTM**  
UNIVERSITI TEKNOLOGI MALAYSIA

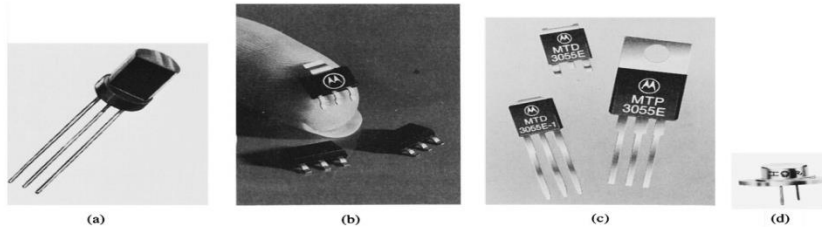
INSPIRING CREATIVE AND INNOVATIVE MINDS

[www.utm.my](http://www.utm.my)

# Transistor - Introduction to Bipolar Junction Transistor (BJT)



- Beside diodes, the most popular semiconductor devices is transistors. Eg: Bipolar Junction Transistor (BJT)
- Transistors are more complex and can be used in many ways
- Most important feature: can amplify signals and as switch
- Amplification can make weak signal strong (make sounds louder and signal levels greater), in general, provide function called *Gain*



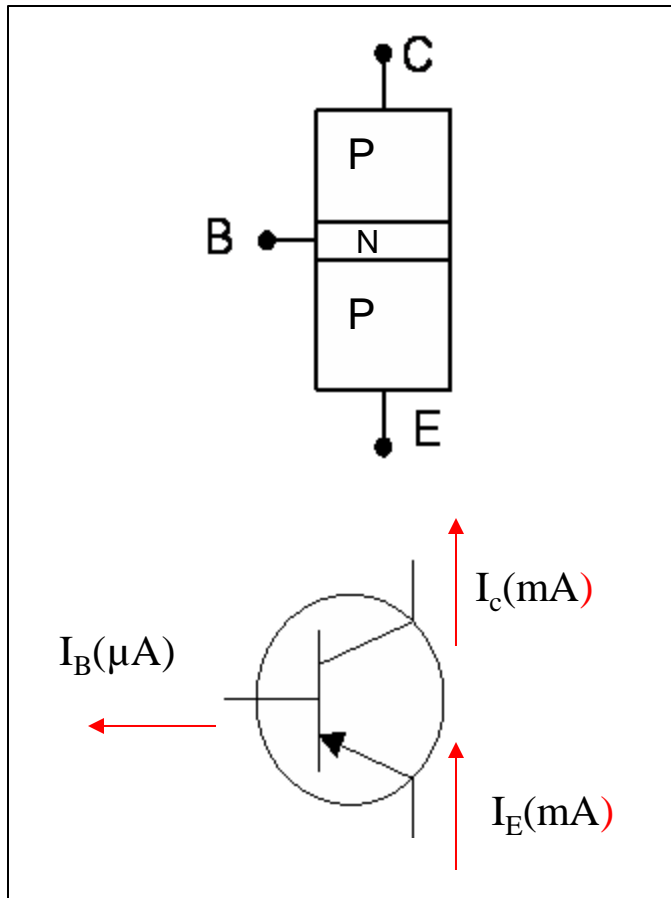


- BJT is bipolar because both holes (+) and electrons (-) will take part in the current flow through the device
  - N-type regions contains free electrons (negative carriers)
  - P-type regions contains free holes (positive carriers)
- 2 types of BJT
  - NPN transistor
  - PNP transistor
- The transistor regions are:
  - Emitter (E) – send the carriers into the base region and then on to the collector
  - Base (B) – acts as control region. It can allow none, some or many carriers to flow
  - Collector (C) – collects the carriers

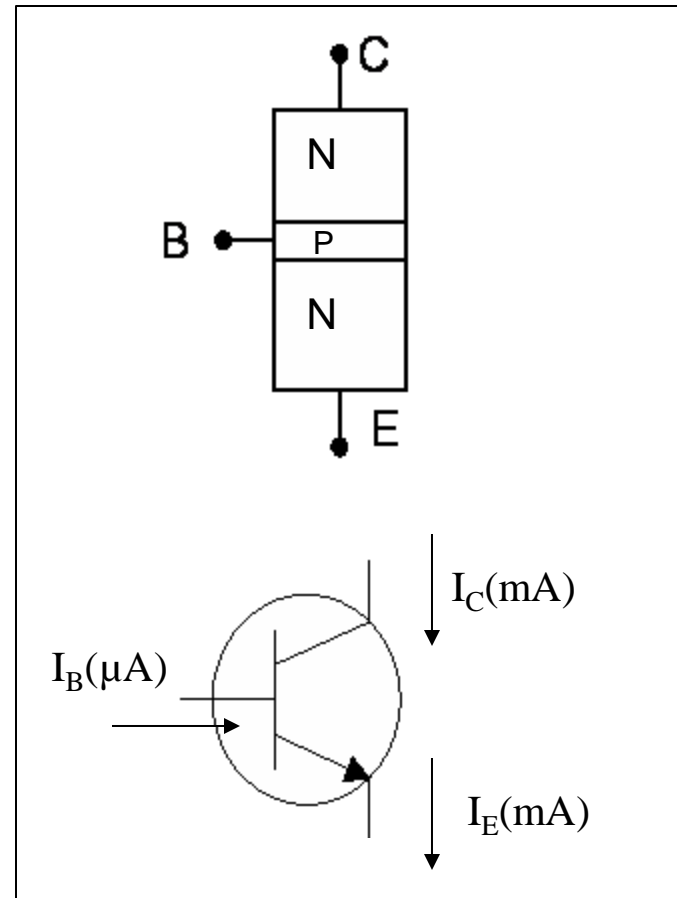
## Structure and Symbol of BJT

[www.utm.my](http://www.utm.my)

### PNP



### NPN



Arrow shows the current flows

## Structure of Transistor

### NPN Transistor

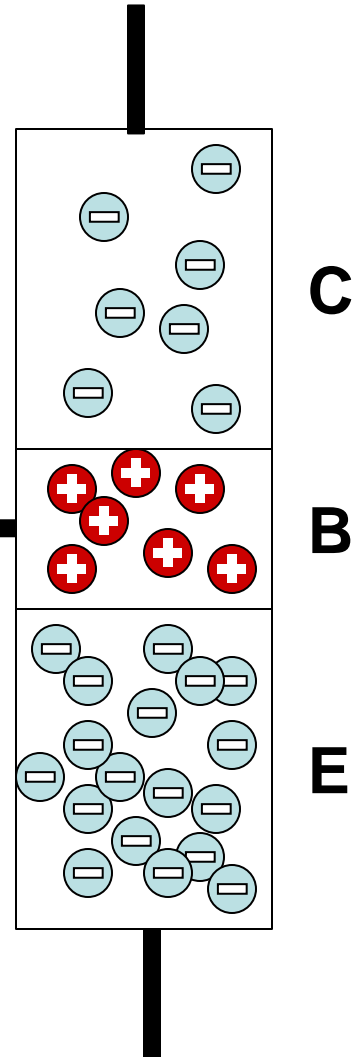
Collector is lightly doped



Base is thin and lightly doped



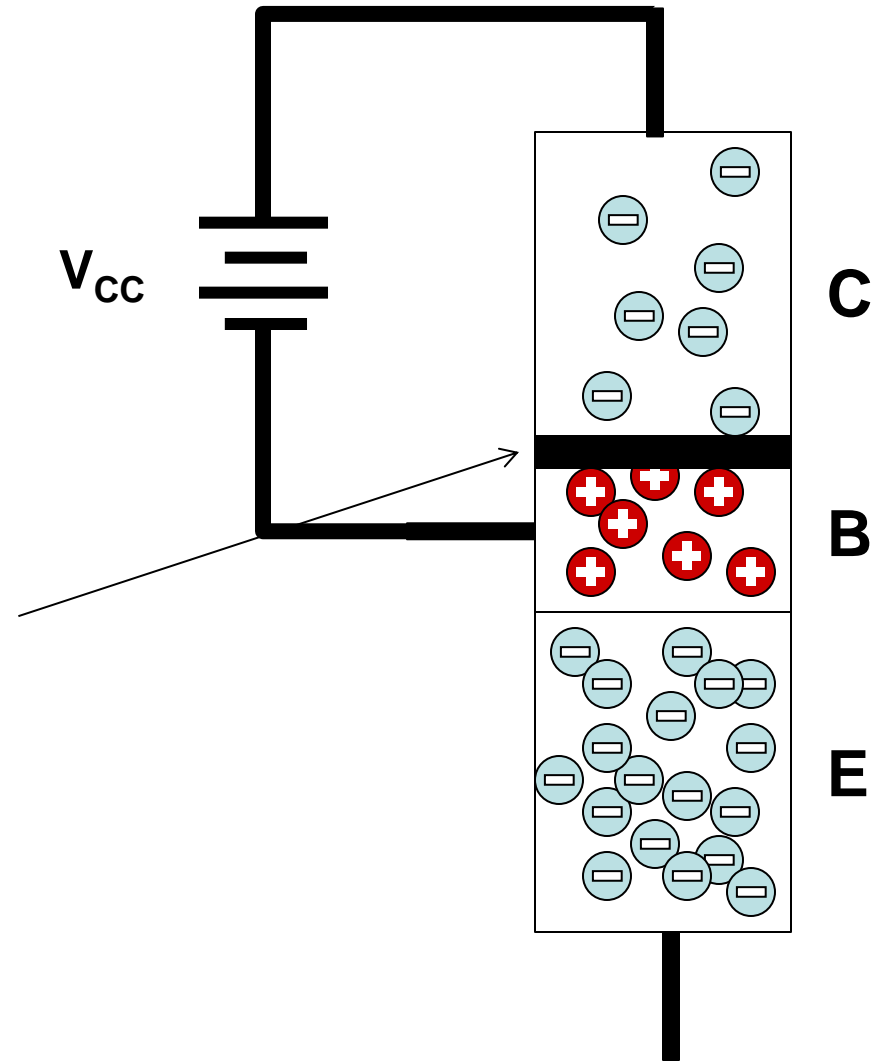
Emitter is heavily doped



## NPN Transistor Bias

No current flows

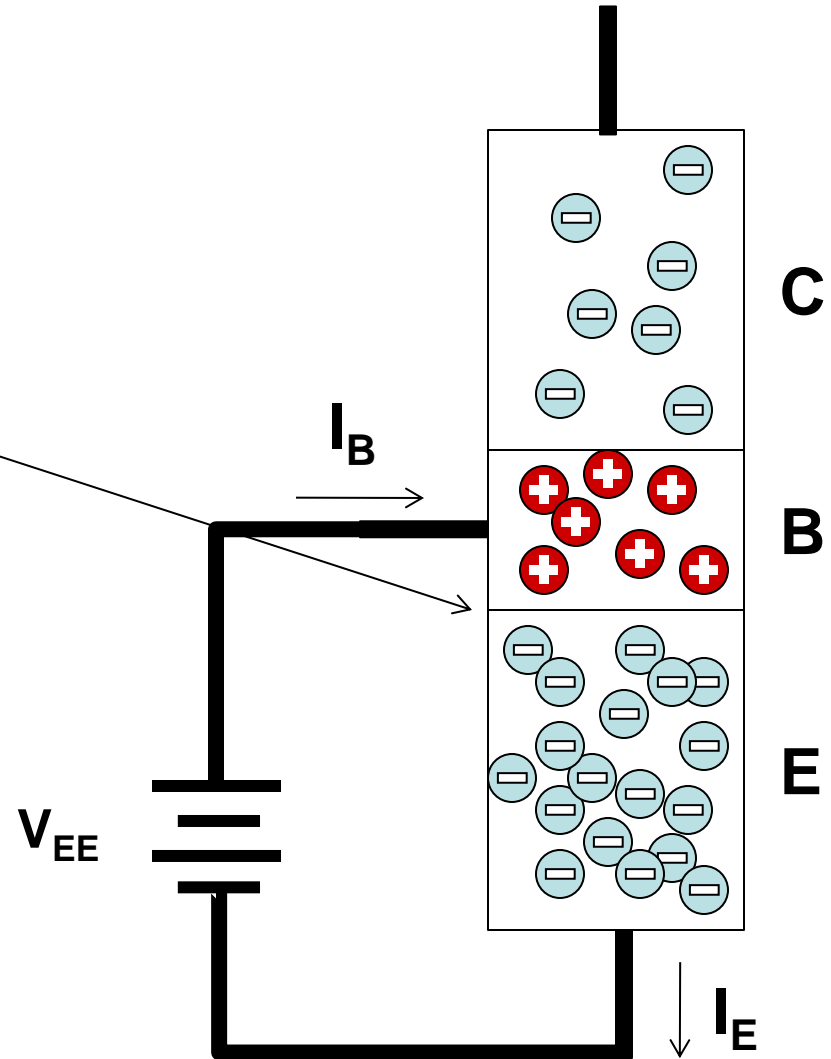
The C-B junction is reverse biased.



## NPN Transistor Bias

**The B-E junction is forward biased.**

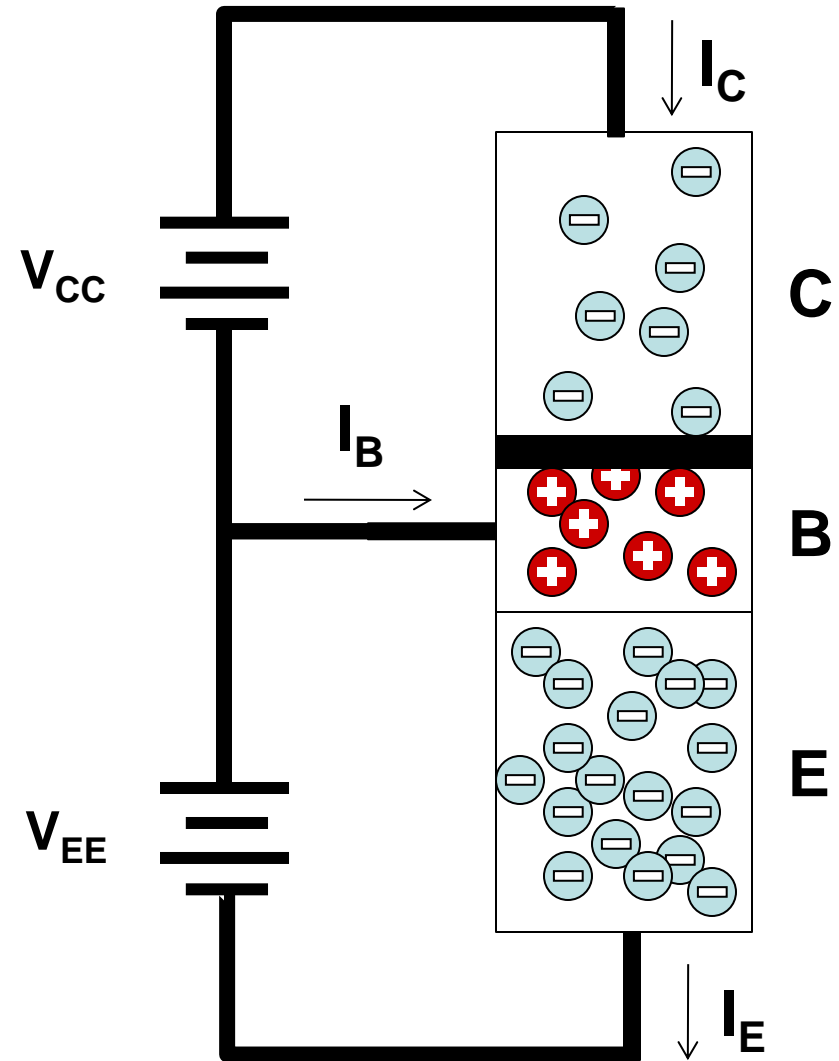
Current flows from B to E



## NPN Transistor Bias

When both junctions are bias,  
current flows everywhere

Applying Kirchoff's current law,  
we obtain  $I_E = I_C + I_B$  and also  
 $I_C = I_{Cmajority} + I_{Cminority}$







## Alpha ( $\alpha$ )

- Also known as DC short current gain,  $h_{FB}$
- Level of  $I_C$  and  $I_E$  due to majority carriers

$$\alpha = \frac{I_C}{I_E}$$

so that

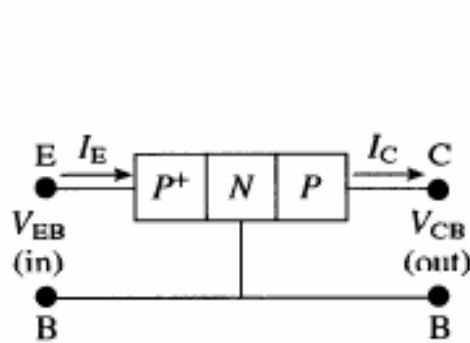
$$I_C = \alpha I_E + I_{CBO}$$

\*Note that  $I_{CBO} = I_{CO}$

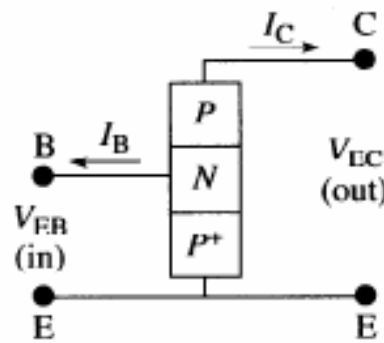
# Transistor Configuration

[www.utm.my](http://www.utm.my)

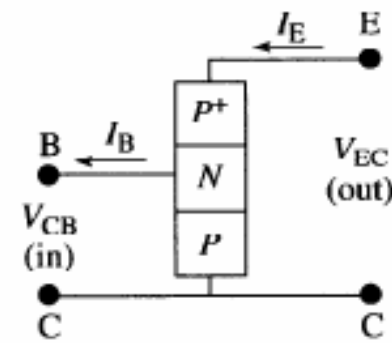
- Transistor configuration – is a connection of transistor to get variety operation.
- 3 types of configuration:
  - *Common Collector.*
  - *Common Base.*
  - *Common Emitter*



(a) Common base



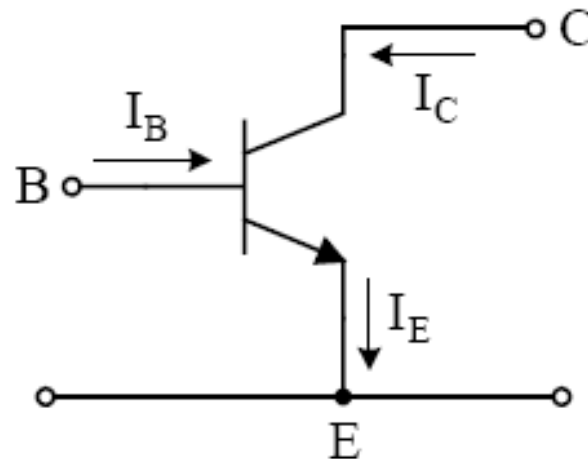
(b) Common emitter



(c) Common collector

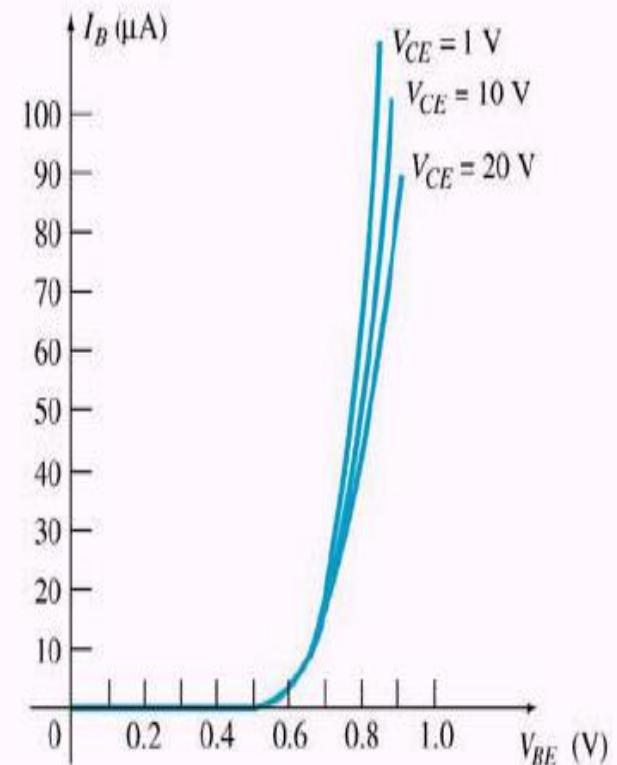
## Common Emitter Configuration

- Emitter terminal is common for input and output circuit
- Input – BE
- Output – CE
- Mostly applied in practical amplifier circuits, since it provides good voltage, current and power gain



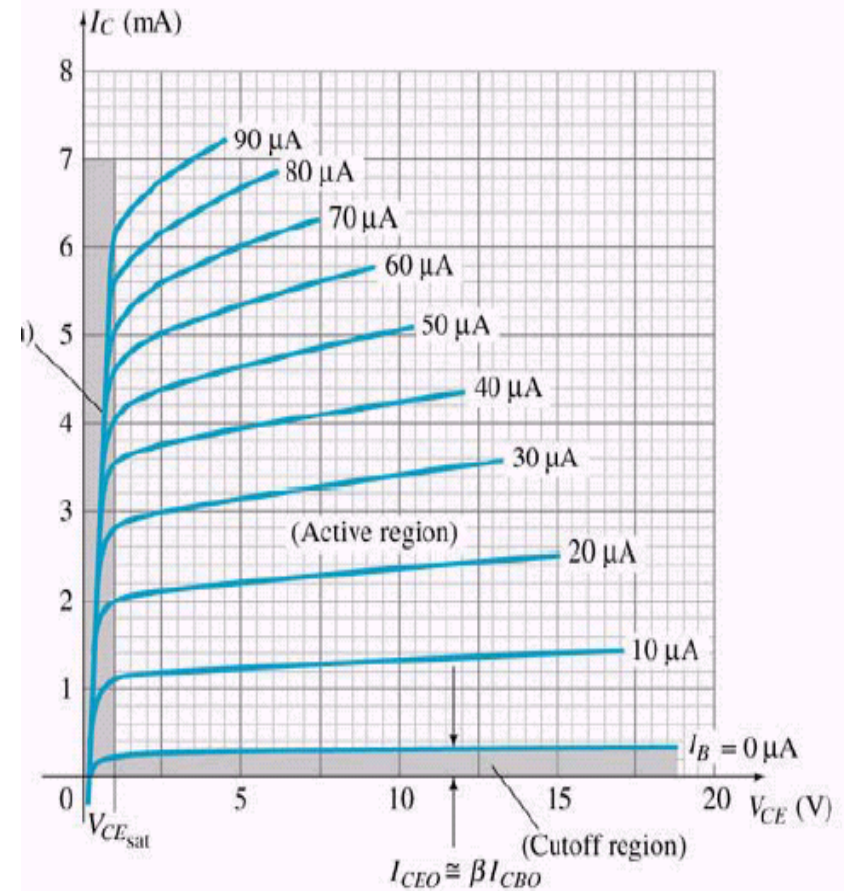
## Input Characteristic

- Input characteristic: input current ( $I_B$ ) against input voltage ( $V_{BE}$ ) for several output voltage ( $V_{CE}$ )
- From the graph
  - $I_B = 0$  A  $V_{BE} < 0.7$  V (Si)
  - $I_B = \text{value}$   $V_{BE} > 0.7$  V (Si)
- The transistor turned on when  $V_{BE} = 0.7$  V



## Output Characteristic

- Output characteristic: output current ( $I_C$ ) against output voltage ( $V_{CE}$ ) for several input current ( $I_B$ )
- 3 operating regions:
  - Saturation region
  - Cut-off region
  - Active region





# I-V Characteristic

- Saturation region – in which both junctions are forward-biased and  $I_C$  increase linearly with  $V_{CE}$
- Cut-off region – where both junctions are reverse-biased, the  $I_B$  is very small, and essentially no  $I_C$  flows,  $I_C$  is essentially zero with increasing  $V_{CE}$
- Active region – in which the transistor can act as a linear amplifier, where the BE junction is forward-biased and BC junction is reverse-biased.  $I_C$  increases drastically although only small changes of  $I_B$ .
- Saturation and cut-off regions – areas where the transistor can operate as a switch
- Active region – area where transistor operates as an amplifier



## Beta ( $\beta$ )

- Also known as DC short current gain,  $h_{FE}$
- Relation between  $I_C$  and  $I_B$

$$\beta = \frac{I_C}{I_B}$$



# Alpha ( $\alpha$ ) and Beta ( $\beta$ )

[www.utm.my](http://www.utm.my)

From  $I_E = I_C + I_B$

We have  $\frac{I_C}{\alpha} = I_C + \frac{I_C}{\beta}$

$$\alpha = \frac{I_C}{I_E} \quad , \quad \beta = \frac{I_C}{I_B}$$

and dividing both side of equation by  $I_C$  results in

$$\frac{1}{\alpha} = 1 + \frac{1}{\beta}$$

or

$$\beta = \alpha\beta + \alpha = (\beta + 1)\alpha$$

so that

$$\alpha = \frac{\beta}{\beta + 1} \quad \text{or} \quad \beta = \frac{\alpha}{1 - \alpha}$$





**UTM**  
UNIVERSITI TEKNOLOGI MALAYSIA

[www.utm.my](http://www.utm.my)

**Let's have a break...**

**INSPIRING CREATIVE AND INNOVATIVE MINDS**